## Onsemi

## **Complementary Power Transistors**

**DPAK For Surface Mount Applications** 

## MJD31 (NPN), MJD32 (PNP)

Designed for general purpose amplifier and low speed switching applications.

## Features

- Lead Formed for Surface Mount Applications in Plastic Sleeves
- Straight Lead Version in Plastic Sleeves ("1" Suffix)
- Lead Formed Version in 16 mm Tape and Reel ("T4" Suffix)
- Electrically Similar to Popular TIP31 and TIP32 Series
- Epoxy Meets UL 94, V-0 @ 0.125 in
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

## **MAXIMUM RATINGS**

Symbol V <sub>CEO</sub>	Max	Unit Vdc
V <sub>CEO</sub>	10	Vde
	40 100	vuc
V <sub>CB</sub>	40 100	Vdc
$V_{\text{EB}}$	5.0	Vdc
I <sub>C</sub>	3.0	Adc
I <sub>CM</sub>	5.0	Adc
Ι <sub>Β</sub>	1.0	Adc
P <sub>D</sub>	15 0.12	W W/°C
P <sub>D</sub>	1.56 0.012	W W/°C
T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C
HBM	3B	V
MM	M3	V
	V <sub>EB</sub> I <sub>C</sub> I <sub>D</sub> P <sub>D</sub> P <sub>D</sub> T <sub>J</sub> , T <sub>stg</sub> HBM MM	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

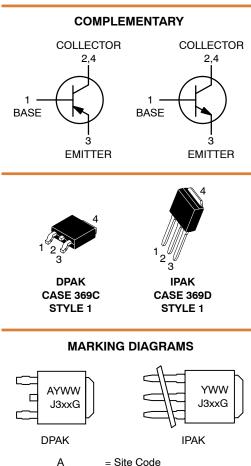
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	8.3	°C/W
Thermal Resistance, Junction-to-Ambient*	$R_{\thetaJA}$	80	°C/W
Lead Temperature for Soldering Purposes	ΤL	260	°C

\*These ratings are applicable when surface mounted on the minimum pad sizes recommended.

## SILICON **POWER TRANSISTORS** 3 AMPERES 40 AND 100 VOLTS **15 WATTS**



= Site Code

= Year = Work Week

Y

WW

хх G

= 1, 1C, 2, or 2C

= Pb-Free Package

## **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

## **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = $25^{\circ}$ C unless otherwise noted)

Characteristic	Symbol	Min	Мах	Unit
OFF CHARACTERISTICS				
Collector-Emitter Sustaining Voltage (Note 1) (I <sub>C</sub> = 30 mAdc, I <sub>B</sub> = 0) MJD31, MJD32 MJD31C, MJD32C	V <sub>CEO(sus)</sub>	40 100		Vdc
Collector Cutoff Current $(V_{CE} = 40 \text{ Vdc}, I_B = 0)$ MJD31, MJD32 $(V_{CE} = 60 \text{ Vdc}, I_B = 0)$ MJD31C, MJD32C	I <sub>CEO</sub>		50 50	μAdc
Collector Cutoff Current ( $V_{CE}$ = Rated $V_{CEO}$ , $V_{EB}$ = 0)	ICES	_	20	μAdc
Emitter Cutoff Current ( $V_{BE} = 5 \text{ Vdc}, I_C = 0$ )	I <sub>EBO</sub>	_	1	mAdc
ON CHARACTERISTICS (Note 1)				
DC Current Gain ( $I_C = 1$ Adc, $V_{CE} = 4$ Vdc) ( $I_C = 3$ Adc, $V_{CE} = 4$ Vdc)	h <sub>FE</sub>	25 10	- 50	
Collector-Emitter Saturation Voltage ( $I_C = 3 \text{ Adc}, I_B = 375 \text{ mAdc}$ )	V <sub>CE(sat)</sub>	-	1.2	Vdc

Base-Emitter On Voltage  $(I_C = 3 \text{ Adc}, V_{CE} = 4 \text{ Vdc})$ 

## DYNAMIC CHARACTERISTICS

Current Gain – Bandwidth Product (Note 2) (I <sub>C</sub> = 500 mAdc, V <sub>CE</sub> = 10 Vdc, f <sub>test</sub> = 1 MHz)	f <sub>T</sub>	3	-	MHz
Small–Signal Current Gain (I <sub>C</sub> = 0.5 Adc, V <sub>CE</sub> = 10 Vdc, f = 1 kHz)	h <sub>fe</sub>	20	-	

V<sub>BE(on)</sub>

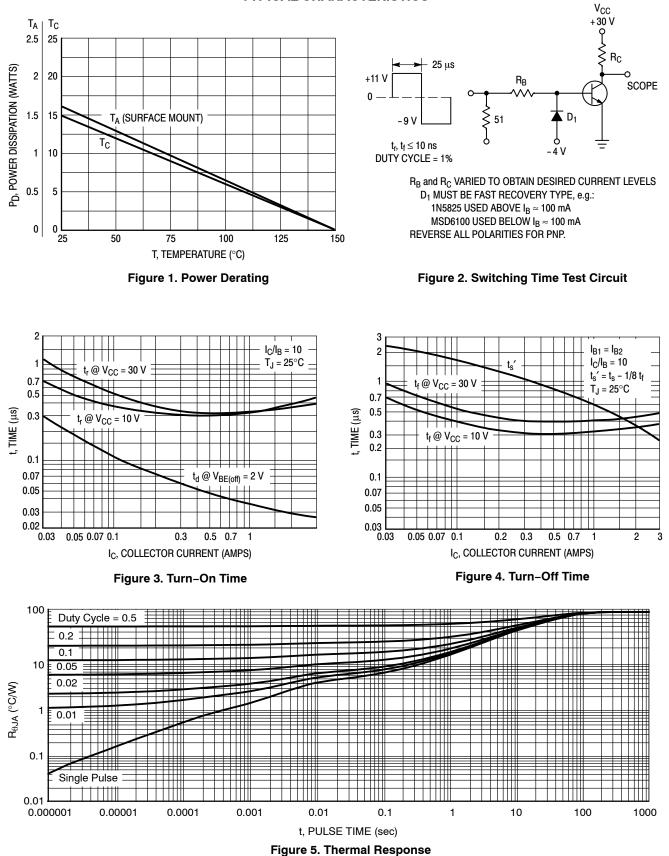
Vdc

1.8

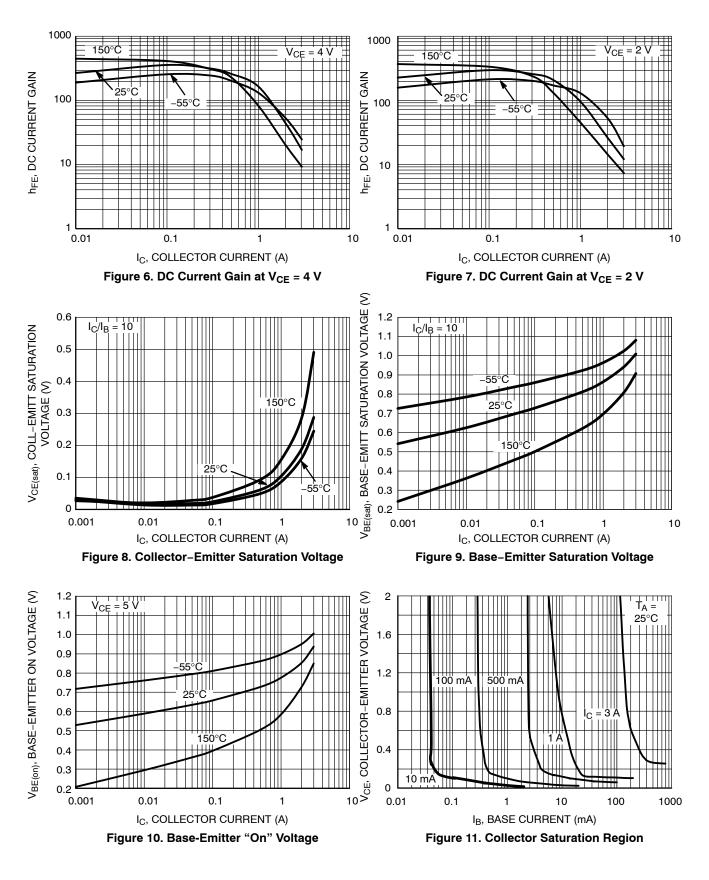
\_

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 1. Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle  $\leq$  2%. 2.  $f_T = |h_{fe}| \bullet f_{test}$ .

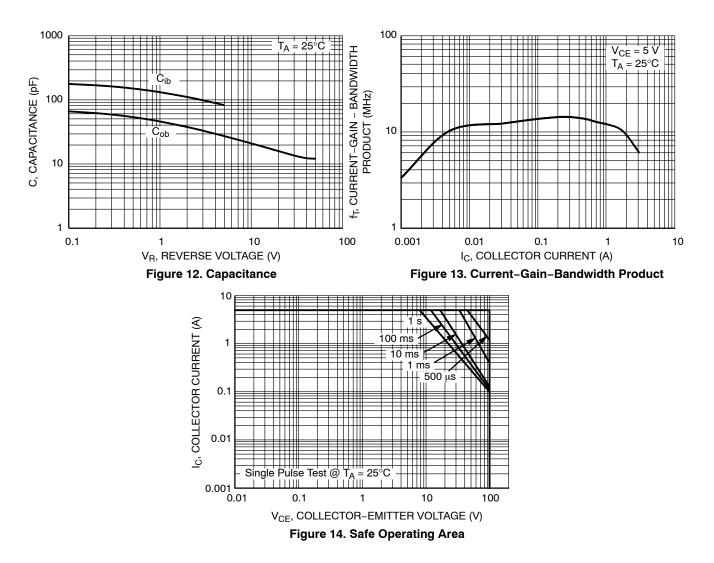
## **TYPICAL CHARACTERISTICS**



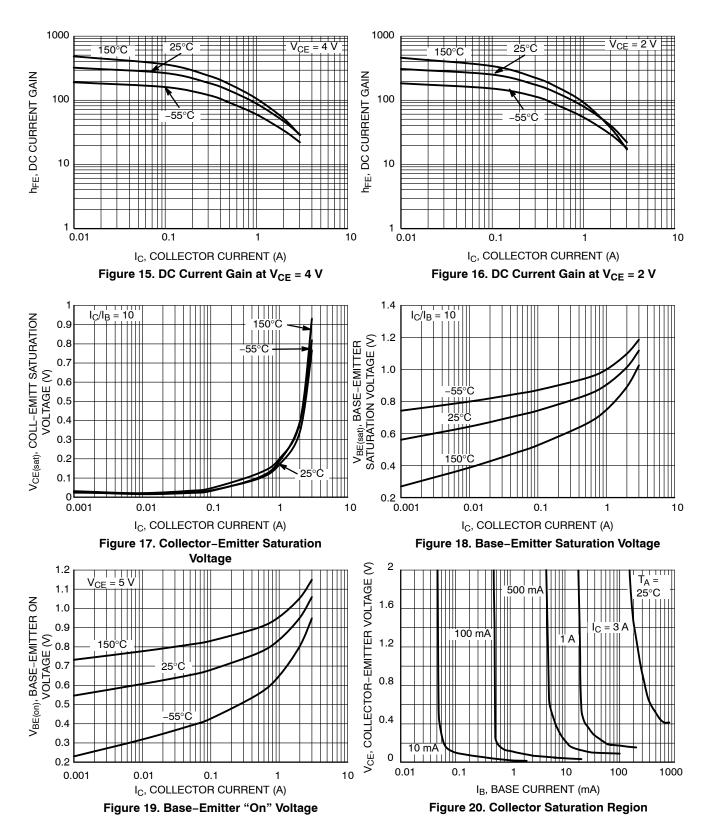
## **TYPICAL CHARACTERISTICS – MJD31, MJD31C (NPN)**



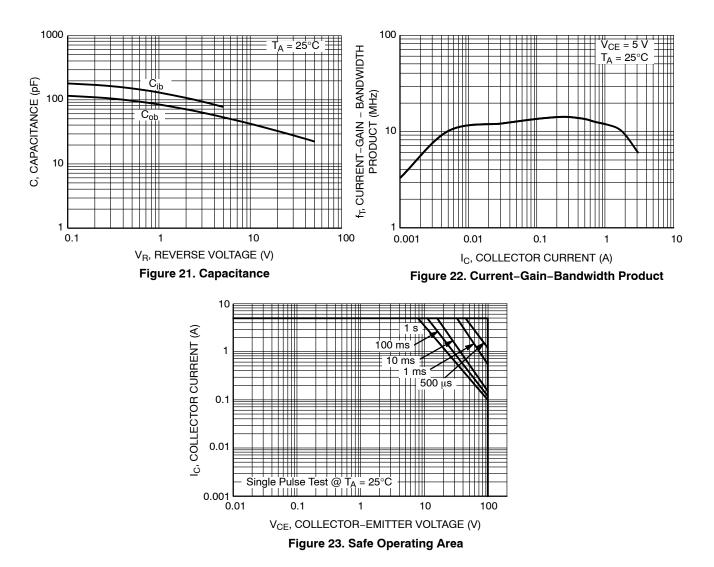
## TYPICAL CHARACTERISTICS - MJD31, MJD31C (NPN)



## TYPICAL CHARACTERISTICS - MJD32, MJD32C (PNP)



## **TYPICAL CHARACTERISTICS**



## **ORDERING INFORMATION**

Device	Package Type	Package	Shipping <sup>†</sup>	
MJD31CG	DPAK (Pb-Free)	369C	75 Units / Rail	
NJVMJD31CG*	DPAK (Pb-Free)	369C	75 Units / Rail	
MJD31C1G	IPAK (Pb-Free)	369D	75 Units / Rail	
MJD31CRLG	DPAK (Pb-Free)	369C	1,800 / Tape & Reel	
NJVMJD31CRLG*	DPAK (Pb-Free)	369C	1,800 / Tape & Reel	
MJD31CT4G	DPAK (Pb-Free)	369C	2,500 / Tape & Reel	
NJVMJD31CT4G*	DPAK (Pb-Free)	369C	2,500 / Tape & Reel	
MJD31T4G	DPAK (Pb-Free)	369C	2,500 / Tape & Reel	
NJVMJD31T4G*	DPAK (Pb-Free)	369C	2,500 / Tape & Reel	
MJD32CG	DPAK (Pb-Free)	369C	75 Units / Rail	
NJVMJD32CG*	DPAK (Pb-Free)	369C	75 Units / Rail	
MJD32CRLG	DPAK (Pb-Free)	369C	1,800 / Tape & Reel	
MJD32CT4G	DPAK (Pb-Free)	369C	2,500 / Tape & Reel	
NJVMJD32CT4G*	DPAK (Pb-Free)	369C	2,500 / Tape & Reel	
MJD32RLG	DPAK (Pb-Free)	369C	1,800 / Tape & Reel	
MJD32T4G	DPAK (Pb-Free)	369C	2,500 / Tape & Reel	
NJVMJD32T4G*	DPAK (Pb–Free)	369C	2,500 / Tape & Reel	

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
\*NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP

Capable.



IPAK CASE 369D-01 **ISSUE C** 

DATE 15 DEC 2010

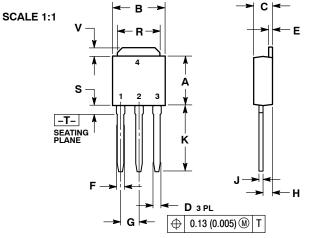
STYLE 1: PIN 1. BASE

2. COLLECTOR

3. EMITTER 4. COLLECTOR

STYLE 5: PIN 1. GATE 2. ANODE 3. CATHODE

4. ANODE



STYLE 2: PIN 1. GATE

STYLE 6: PIN 1. MT1 2. MT2 3. GATE

4. MT2

DRAIN
SOURCE

4. DRAIN

STYLE 3: PIN 1. ANODE

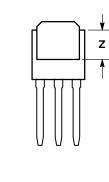
CATHODE
ANODE

4. CATHODE

COLLECTOR

STYLE 7: PIN 1. GATE 2. COLLECTOR 3. EMITTER

4.



STYLE 4: PIN 1. CATHODE

ANODE
GATE

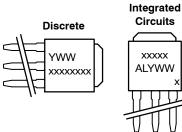
4. ANODE

	INCHES		MILLIMETER	
DIM	MIN	MAX	MIN	MAX
Α	0.235	0.245	5.97	6.35
В	0.250	0.265	6.35	6.73
С	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
Е	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.090 BSC		2.29 BSC	
Н	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
Κ	0.350	0.380	8.89	9.65
R	0.180	0.215	4.45	5.45
S	0.025	0.040	0.63	1.01
V	0.035	0.050	0.89	1.27
Ζ	0.155		3.93	

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

NOTES:

## MARKING DIAGRAMS

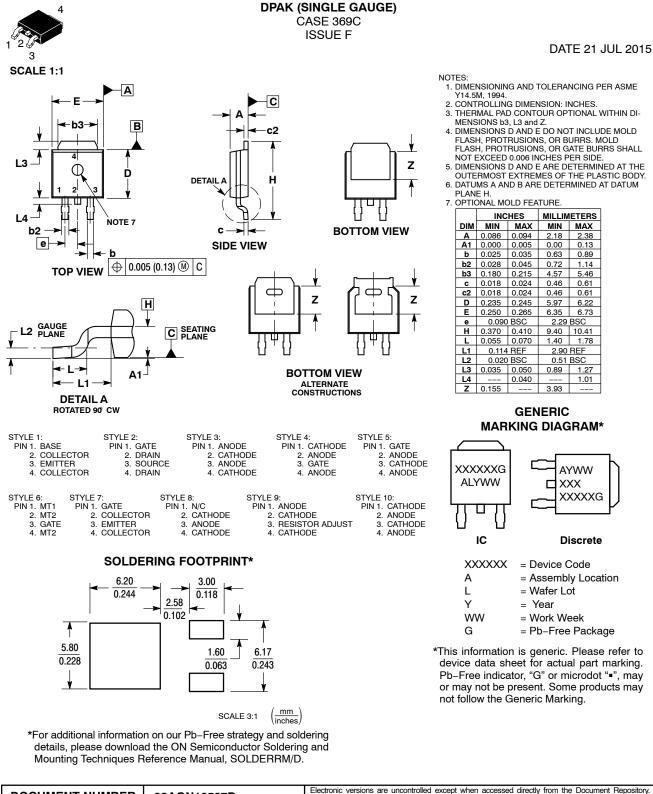


xxxxxxxx = Device Code А = Assembly Location IL = Wafer Lot Y = Year WW = Work Week

DOCUMENT NUMBER:	98AON10528D	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION:	SCRIPTION: IPAK (DPAK INSERTION MOUNT) PA				
ON Semiconductor and (III) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.					

© Semiconductor Components Industries, LLC, 2019

# onsemi



onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and calcular performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

### TECHNICAL SUPPORT

onsemi Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative

 $\Diamond$